

# DATA SHEET

# N-Channel Silicon MOSFET SCH1417—General-Purpose Switching Device **Applications**

# **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 1.8V drive.

# Specifications

# Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		15	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	۱D		1.8	A
Drain Current (Pulse)	IDP	PW≤10µs, duty cycle≤1%	7.2	A
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	0.65	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	15			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =15V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	0.4		1.3	V
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =1A	1.5	2.6		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	ID=1A, VGS=4V		120	160	mΩ
	RDS(on)2	ID=0.5A, VGS=2.5V		165	240	mΩ
	R <sub>DS</sub> (on)3	ID=0.1A, VGS=1.8V		230	350	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		105		pF
Output Capacitance	Coss	VDS=10V, f=1MHz		30		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		24		pF
Turn-ON Delay Time	t <sub>d</sub> (on)	See specified Test Circuit.		7.8		ns
Rise Time	tr	See specified Test Circuit.		27		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		18		ns
Fall Time	tf	See specified Test Circuit.		22		ns

Marking : KS

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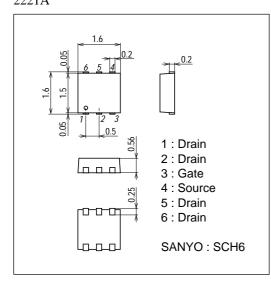
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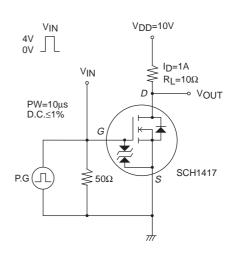
Continued from preceding page. Parameter	Symbol	Conditions		Ratings		
	Gymbol		min	typ	max	Unit
Total Gate Charge	Qg	VDS=10V, VGS=4V, ID=1.8A		1.86		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =4V, I <sub>D</sub> =1.8A		0.33		nC
Gate-to-Drain "Miller" Charge	Qgd	VDS=10V, VGS=4V, ID=1.8A		0.55		nC
Diode Forward Voltage	VSD	IS=1.8A, VGS=0		0.88	1.2	V

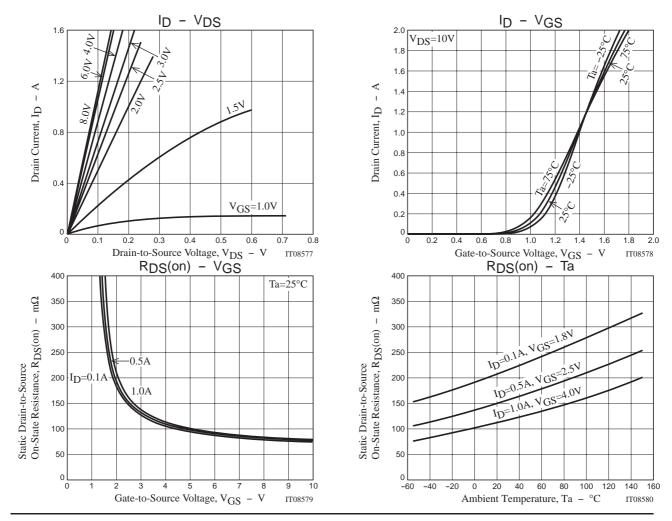
## **Package Dimensions**

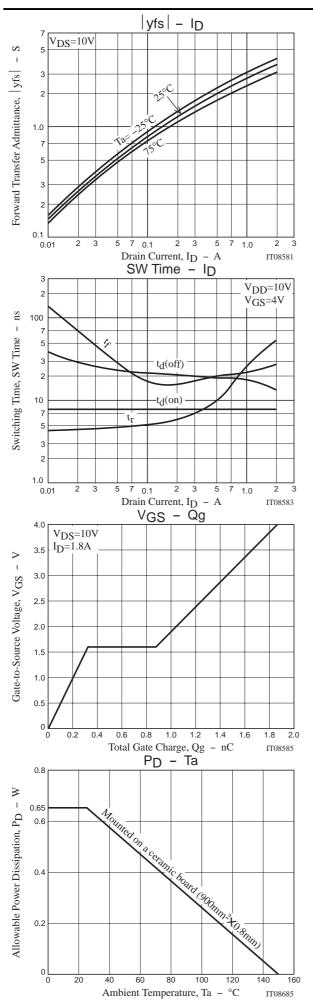
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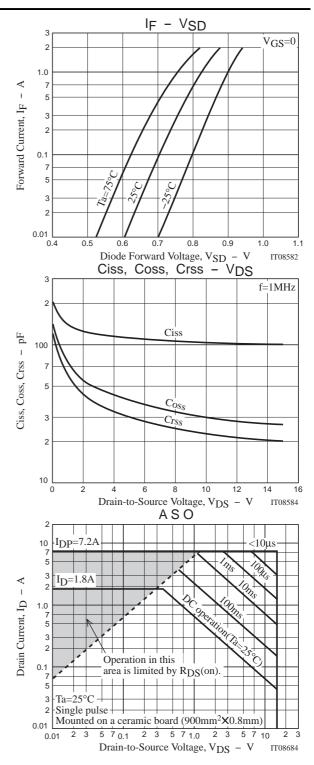


# **Switching Time Test Circuit**









Note on usage : Since the SCH1417 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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